



P-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

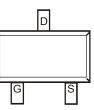
- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (approximate)







Drain



ESD PROTECTED

Top View

Equivalent Circuit

Top View

Ordering Information (Note 4)

Part Number	Case	Packaging
DMG1013UW-7	SOT-323	3000 / Tape & Reel

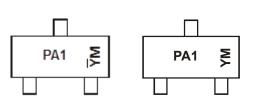
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



PA1 = Product Type Marking Code

YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) $\overline{Y}M$ = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or \overline{Y} = Year (ex: A = 2013)

M = Month (ex: 9 = September)

Chengdu A/T Site

e Shanghai A/T Site

Date	Code	Key

Year	2008	2	009	2010	2	011	2012		2013	2014		2015
Code	V		W	Х		Y	Z		А	В		С
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Cha	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-20	V		
Gate-Source Voltage			V _{GSS}	±6	V
Continuous Drain Current (Note 5)	Steady State	T _A = +25°C T _A = +85°C	Ι _D	-0.82 -0.54	А
Pulsed Drain Current (Note 6)	I _{DM}	-6	А		

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	0.31	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R _{0JA}	398	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout. 6. Repetitive rating, pulse width limited by junction temperature.

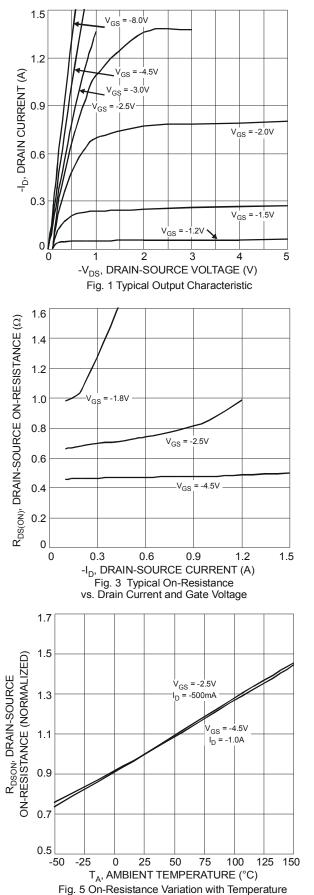
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

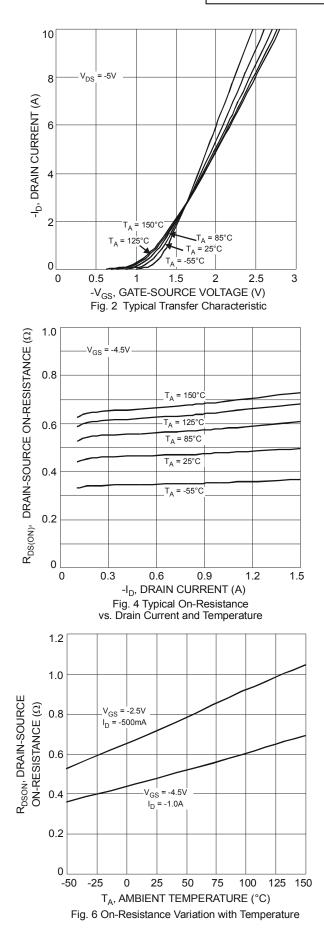
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20	-	-	V	V _{GS} = 0V, I _D = -250µA
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	-	-	-100	nA	V _{DS} = -20V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	-	-	±2.0	μA	V_{GS} = ±4.5V, V_{DS} = 0V
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(th)}	-0.5	-	-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
			0.5	0.75		V_{GS} = -4.5V, I_{D} = -430mA
Static Drain-Source On-Resistance	R _{DS (ON)}	-	0.7	1.05	Ω	V_{GS} = -2.5V, I_{D} = -300mA
			1.0	1.5		V _{GS} = -1.8V, I _D = -150mA
Forward Transfer Admittance	Y _{fs}	-	0.9	-	S	V _{DS} = -10V, I _D = -250mA
Diode Forward Voltage	V _{SD}		-0.8	-1.2	V	V _{GS} = 0V, I _S = -150mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	-	59.76	-	pF	
Output Capacitance	Coss	-	12.07	-	pF	V _{DS} = -16V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	-	6.36	-	pF	1 - 1.00012
Total Gate Charge	Qg	-	622.4	-	рС	(1 - 45)(1)(1 - 40)(1)
Gate-Source Charge	Q _{gs}	-	100.3	-	рС	−V _{GS} = -4.5V, V _{DS} = -10V, −I _D = -250mA
Gate-Drain Charge	Q _{gd}	-	132.2	-	рС	ID23011A
Turn-On Delay Time	t _{D(on)}	-	5.1	-	ns	
Turn-On Rise Time	tr	-	8.1	-	ns	$V_{DD} = -10V, V_{GS} = -4.5V,$
Turn-Off Delay Time	t _{D(off)}	-	28.4	-	ns	$R_{L} = 47\Omega, R_{G} = 10\Omega,$
Turn-Off Fall Time	t _f	-	20.7	-	ns	– I _D = -200mA

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:

DMG1013UW







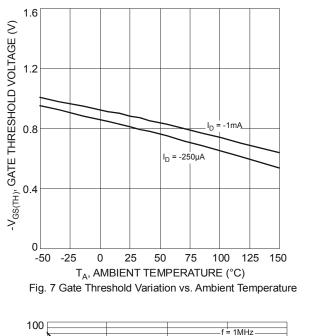
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C, CAPACITANCE (pF)

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1 _____0



C_{iss}

Coss

C_{rss}.

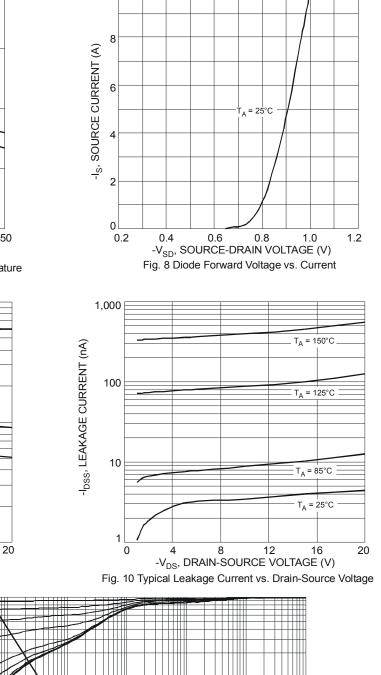
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-V_{DS}, DRAIN-SOURCE VOLTAGE (V) Fig. 9 Typical Total Capacitance

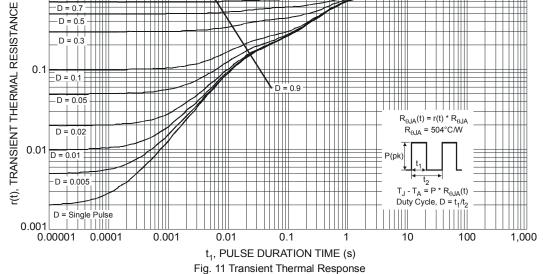
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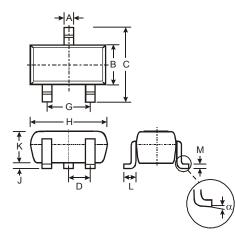


DMG1013UW Document number: DS31861 Rev. 3 - 2



Package Outline Dimensions

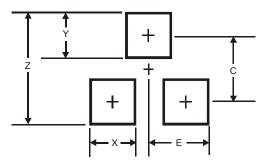
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT-323							
Dim	Min	Max	Тур				
Α	0.25	0.40	0.30				
В	1.15	1.35	1.30				
С	2.00	2.20	2.10				
D	-	-	0.65				
G	1.20	1.40	1.30				
Н	1.80	2.20	2.15				
J	0.0	0.10	0.05				
κ	0.90	1.00	0.95				
L	0.25	0.40	0.30				
М	0.10	0.18	0.11				
α	0°	8°	-				
All	All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0



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